## MC10EP90, MC100EP90

## Translator, Triple ECL Input to LVPECL / PECL Output

## Description

The MC10/100EP90 is a TRIPLE ECL TO LVPECL/PECL translator. The device receives differential LVECL or ECL signals and translates them to differential LVPECL or PECL output signals.
A $V_{B B}$ output is provided for interfacing with Single-Ended LVECL or ECL signals at the input. If a Single-Ended input is to be used the $\mathrm{V}_{\mathrm{BB}}$ output should be connected to the D input. The active signal would then drive the D input. When used the $\mathrm{V}_{\mathrm{BB}}$ output should be bypassed to ground by a $0.01 \mu \mathrm{~F}$ capacitor. The $\mathrm{V}_{\mathrm{BB}}$ output is designed to act as the switching reference for the EP90 under Single-Ended input switching conditions, as a result this pin can only source/sink up to 0.5 mA of current.

To accomplish the level translation the EP90 requires three power rails. The $\mathrm{V}_{\mathrm{CC}}$ supply should be connected to the positive supply, and the $\mathrm{V}_{\mathrm{EE}}$ connected to the negative supply.

The 100 Series contains temperature compensation.

## Features

- 260 ps Typical Propagation Delay
- Maximum Frequency > 3 GHz Typical
- Voltage Supplies $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ to $5.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}}=-3.0 \mathrm{~V}$ to -5.5 V , GND $=0 \mathrm{~V}$
- Open Input Default State
- Safety Clamp on Inputs
- Fully Differential Design
- Q Output Will Default LOW with Inputs Open or at $\mathrm{V}_{\mathrm{EE}}$
- VBB Output
- These are $\mathrm{Pb}-$ Free Devices*

[^0]ORDERING INFORMATION
See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.
ON Semiconductor ${ }^{\circledR}$
http://onsemi.com

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## MC10EP90, MC100EP90



Warning: All $\mathrm{V}_{\mathrm{CC}}, \mathrm{V}_{\mathrm{EE}}$ and $G N D$ pins must be externally connected to Power Supply to guarantee proper operation.

Figure 1. TSSOP-20 (Top View) and Logic Diagram
Table 1. PIN DESCRIPTION

| PIN | FUNCTION |
| :--- | :--- |
| $\mathrm{Q}(0: 2), \overline{\mathrm{Q}}(0: 2)$ | Differential LVPECL or PECL Outputs |
| $\mathrm{D}(0: 2)^{\star}, \overline{\mathrm{D}}(0: 2)^{*}$ | Differential LVECL or ECL Inputs |
| $\mathrm{V}_{\mathrm{CC}}$ | Positive Supply |
| GND | Ground |
| $\mathrm{V}_{\mathrm{EE}}$ | Negative Supply |
| $\mathrm{V}_{\mathrm{BB}}$ | Output Reference Supply |

* Pins will default LOW when left open.

Table 2. FUNCTION TABLE

| Function | $\mathrm{V}_{\mathbf{C C}}$ | $\mathbf{G N D}$ | $\mathbf{V}_{\text {EE }}$ |
| :--- | :--- | :---: | :---: |
| -5 V ECL to 5 V PECL | 5 V | 0 V | -5 V |
| -5 V ECL to 3.3 V PECL | 3.3 V | 0 V | -5 V |
| -3.3 V ECL to 5 V PECL | 5 V | 0 V | -3.3 V |
| -3.3 V ECL to 3.3 V PECL | 3.3 V | 0 V | -3.3 V |

Table 3. ATTRIBUTES

| Characteristics | Value |  |
| :---: | :---: | :---: |
| Internal Input Pulldown Resistor | $75 \mathrm{k} \Omega$ |  |
| Internal Input Pullup Resistor | N/A |  |
| ESD ProtectionHuman Body Model <br> Machine Model <br> Charged Device Model | $\begin{gathered} >2 \mathrm{kV} \\ >200 \mathrm{~V} \\ >2 \mathrm{kV} \end{gathered}$ |  |
| Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1) | Pb Pkg | Pb-Free Pkg |
| TSSOP-20 | Level 1 | Level 1 |
| Flammability Rating Oxygen Index: 28 to 34 | UL 94 V-0 @ 0.125 in |  |
| Transistor Count | 350 Devices |  |
| Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test |  |  |

1. For additional information, refer to Application Note AND8003/D.

## MC10EP90, MC100EP90

Table 4. MAXIMUM RATINGS

| Symbol | Parameter | Condition 1 | Condition 2 | Rating | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | PECL Mode Power Supply | GND $=0 \mathrm{~V}$ |  | 6 | V |
| $\mathrm{V}_{\mathrm{EE}}$ | NECL Mode Power Supply | GND $=0 \mathrm{~V}$ |  | -6 | V |
| $\mathrm{V}_{1}$ | PECL Mode Input Voltage NECL Mode Input Voltage | $\begin{aligned} & \text { GND }=0 \mathrm{~V} \\ & \text { GND }=0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~V}_{\mathrm{I}} \geq \mathrm{V}_{\mathrm{EE}} \end{aligned}$ | $\begin{gathered} \hline 6 \\ -6 \end{gathered}$ | $\begin{aligned} & \hline \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{I}_{\text {out }}$ | Output Current | Continuous Surge |  | $\begin{gathered} 50 \\ 100 \end{gathered}$ | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $\mathrm{I}_{\mathrm{BB}}$ | $\mathrm{V}_{\mathrm{BB}}$ Sink/Source |  |  | $\pm 0.5$ | mA |
| $\mathrm{T}_{\mathrm{A}}$ | Operating Temperature Range |  |  | -40 to +85 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | Storage Temperature Range |  |  | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\theta_{\text {JA }}$ | Thermal Resistance (Junction-to-Ambient) | $\begin{array}{\|l\|} \hline 0 \mathrm{lfpm} \\ 500 \mathrm{lfpm} \end{array}$ | $\begin{aligned} & \hline \text { TSSOP-20 } \\ & \text { TSSOP-20 } \end{aligned}$ | $\begin{aligned} & 140 \\ & 100 \end{aligned}$ | $\begin{aligned} & { }^{\circ} \mathrm{C} / \mathrm{W} \\ & { }^{\circ} \mathrm{C} / \mathrm{W} \end{aligned}$ |
| $\theta_{\text {Jc }}$ | Thermal Resistance (Junction-to-Case) | Standard Board | TSSOP-20 | 23 to 41 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{T}_{\text {sol }}$ | Wave SolderPb <br> $\mathrm{Pb}-\mathrm{Free}$ | $\begin{aligned} & <2 \text { to } 3 \sec @ 248^{\circ} \mathrm{C} \\ & <2 \text { to } 3 \sec @ 260^{\circ} \mathrm{C} \end{aligned}$ |  | $\begin{aligned} & 265 \\ & 265 \end{aligned}$ | ${ }^{\circ} \mathrm{C}$ |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 5. 10EP DC CHARACTERISTICS $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}}=-5.5 \mathrm{~V}$ to -3.0 V ; $\mathrm{GND}=0 \mathrm{~V}$ (Note 2)

| Symbol | Characteristic | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max |  |
| $\mathrm{I}_{\text {EE }}$ | Negative Power Supply Current | 5 | 13 | 20 | 5 | 13 | 20 | 5 | 13 | 20 | mA |
| ICC | Positive Power Supply Current | 43 | 55 | 67 | 43 | 55 | 67 | 43 | 55 | 67 | mA |
| $\mathrm{V}_{\mathrm{OH}}$ | Output HIGH Voltage (Note 3) | 2165 | 2290 | 2415 | 2230 | 2355 | 2480 | 2290 | 2415 | 2540 | mV |
| $\mathrm{V}_{\text {OL }}$ | Output LOW Voltage (Note 3) | 1365 | 1490 | 1615 | 1430 | 1555 | 1680 | 1490 | 1615 | 1740 | mV |
| $\mathrm{V}_{1 \mathrm{H}}$ | Input HIGH Voltage (Single-Ended) | -1210 |  | -885 | -1145 |  | -820 | -1085 |  | -760 | mV |
| $\mathrm{V}_{\text {IL }}$ | Input LOW Voltage (Single-Ended) | -1935 |  | -1610 | -1870 |  | -1545 | -1810 |  | -1485 | mV |
| $\mathrm{V}_{\mathrm{BB}}$ | Output Voltage Reference | -1510 | -1410 | -1310 | -1445 | -1345 | -1245 | -1385 | -1285 | -1185 | mV |
| $\mathrm{V}_{\text {IHCMR }}$ | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 4) | $\mathrm{V}_{\mathrm{EE}}+2.0$ |  | 0.0 | $\mathrm{V}_{\mathrm{EE}+}+2.0$ |  | 0.0 | $\mathrm{V}_{\mathrm{EE}+2.0}$ |  | 0.0 | V |
| $\mathrm{IIH}^{\text {H }}$ | Input HIGH Current |  |  | 150 |  |  | 150 |  |  | 150 | $\mu \mathrm{A}$ |
| ILL | Input LOW Current | 0.5 |  |  | 0.5 |  |  | 0.5 |  |  | $\mu \mathrm{A}$ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
2. Input and output parameters vary $1: 1$ with $\mathrm{V}_{\mathrm{CC}}$.
3. All loading with $50 \Omega$ to $\mathrm{V}_{\mathrm{CC}}-2.0 \mathrm{~V}$.
4. $\mathrm{V}_{\text {IHCMR }}$ min varies $1: 1$ with $\mathrm{V}_{\text {EE }}$, max varies $1: 1$ with $\mathrm{V}_{\mathrm{CC}}$. The $\mathrm{V}_{\text {IHCMR }}$ range is referenced to the most positive side of the differential input signal.

Table 6. 10EP DC CHARACTERISTICS $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}}=-5.5 \mathrm{~V}$ to -3.0 V ; $\mathrm{GND}=0 \mathrm{~V}$ (Note 5)

| Symbol | Characteristic | -40 ${ }^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max |  |
| $\mathrm{I}_{\text {EE }}$ | Negative Power Supply Current | 5 | 13 | 20 | 5 | 13 | 20 | 5 | 13 | 20 | mA |
| ICC | Positive Power Supply Current | 43 | 55 | 67 | 43 | 55 | 67 | 43 | 55 | 67 | mA |
| $\mathrm{V}_{\mathrm{OH}}$ | Output HIGH Voltage (Note 6) | 3865 | 3990 | 4115 | 3930 | 4055 | 4180 | 3990 | 4115 | 4240 | mV |
| V ${ }_{\text {OL }}$ | Output LOW Voltage (Note 6) | 3065 | 3190 | 3315 | 3130 | 3255 | 3380 | 3190 | 3315 | 3440 | mV |
| $\mathrm{V}_{1 \mathrm{H}}$ | Input HIGH Voltage (Single-Ended) | -1210 |  | -885 | -1145 |  | -820 | -1085 |  | -760 | mV |
| $\mathrm{V}_{\mathrm{IL}}$ | Input LOW Voltage (Single-Ended) | -1935 |  | -1610 | -1870 |  | -1545 | -1810 |  | -1485 | mV |
| $\mathrm{V}_{\mathrm{BB}}$ | Output Voltage Reference | -1510 | -1410 | -1310 | -1445 | -1345 | -1245 | -1385 | -1285 | -1185 | mV |
| VIHCMR | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 7) | $\mathrm{V}_{\mathrm{EE}+2.0}$ |  | 0.0 | $\mathrm{V}_{\mathrm{EE}+}+2.0$ |  | 0.0 | $\mathrm{V}_{\mathrm{EE}+2.0}$ |  | 0.0 | V |
| $\mathrm{I}_{\mathrm{H}}$ | Input HIGH Current |  |  | 150 |  |  | 150 |  |  | 150 | $\mu \mathrm{A}$ |
| ILL | Input LOW Current | 0.5 |  |  | 0.5 |  |  | 0.5 |  |  | $\mu \mathrm{A}$ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm . Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
5. Input and output parameters vary $1: 1$ with $\mathrm{V}_{\mathrm{CC}}$.
6. All loading with $50 \Omega$ to $\mathrm{V}_{\mathrm{CC}}-2.0 \mathrm{~V}$.
7. $\mathrm{V}_{\mathrm{IHCMR}}$ min varies $1: 1$ with $\mathrm{V}_{\mathrm{EE}}$, max varies $1: 1$ with $\mathrm{V}_{\mathrm{CC}}$. The $\mathrm{V}_{\mathrm{IHCMR}}$ range is referenced to the most positive side of the differential input signal.

Table 7. 100EP DC CHARACTERISTICS $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}}=-5.5 \mathrm{~V}$ to -3.0 V ; GND $=0 \mathrm{~V}$ (Note 8)

| Symbol | Characteristic | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max |  |
| $l_{\text {EE }}$ | Negative Power Supply Current | 5 | 13 | 20 | 5 | 13 | 20 | 5 | 13 | 20 | mA |
| ICC | Positive Power Supply Current | 45 | 58 | 70 | 50 | 62 | 75 | 53 | 65 | 78 | mA |
| $\mathrm{V}_{\mathrm{OH}}$ | Output HIGH Voltage (Note 9) | 2155 | 2280 | 2405 | 2155 | 2280 | 2405 | 2155 | 2280 | 2405 | mV |
| $\mathrm{V}_{\text {OL }}$ | Output LOW Voltage (Note 9) | 1305 | 1480 | 1605 | 1305 | 1480 | 1605 | 1305 | 1480 | 1605 | mV |
| $\mathrm{V}_{\mathrm{IH}}$ | Input HIGH Voltage (Single-Ended) | -1225 |  | -885 | -1225 |  | -885 | -1225 |  | -885 | mV |
| $\mathrm{V}_{\text {IL }}$ | Input LOW Voltage (Single-Ended) | -1995 |  | -1625 | -1995 |  | -1625 | -1995 |  | -1625 | mV |
| $\mathrm{V}_{\mathrm{BB}}$ | Output Voltage Reference | -1525 | -1425 | -1325 | -1525 | -1425 | -1325 | -1525 | -1425 | -1325 | mV |
| $\mathrm{V}_{\text {IHCMR }}$ | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 10) | $\mathrm{V}_{\mathrm{EE}}+2.0$ |  | 0.0 | $\mathrm{V}_{\mathrm{EE}}+2.0$ |  | 0.0 | $\mathrm{V}_{\mathrm{EE}+}+2.0$ |  | 0.0 | V |
| $\mathrm{I}_{\mathrm{H}}$ | Input HIGH Current |  |  | 150 |  |  | 150 |  |  | 150 | $\mu \mathrm{A}$ |
| ILL | Input LOW Current | 0.5 |  |  | 0.5 |  |  | 0.5 |  |  | $\mu \mathrm{A}$ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
8. Input and output parameters vary $1: 1$ with $V_{C C}$.
9. All loading with $50 \Omega$ to $\mathrm{V}_{\mathrm{CC}}-2.0 \mathrm{~V}$.
10. $\mathrm{V}_{\text {IHCMR }}$ min varies $1: 1$ with $\mathrm{V}_{\mathrm{EE}}$, max varies $1: 1$ with $\mathrm{V}_{\mathrm{CC}}$. The $\mathrm{V}_{\mathrm{IHCMR}}$ range is referenced to the most positive side of the differential input signal.

Table 8. 100EP DC CHARACTERISTICS $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}}=-5.5 \mathrm{~V}$ to -3.0 V ; $\mathrm{GND}=0 \mathrm{~V}$ (Note 11)

| Symbol | Characteristic | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max |  |
| $\mathrm{l}_{\text {EE }}$ | Negative Power Supply Current | 5 | 13 | 20 | 5 | 13 | 20 | 5 | 13 | 20 | mA |
| ICc | Positive Power Supply Current | 45 | 58 | 70 | 50 | 62 | 75 | 53 | 65 | 78 | mA |
| $\mathrm{V}_{\mathrm{OH}}$ | Output HIGH Voltage (Note 12) | 3855 | 3980 | 4105 | 3855 | 3980 | 4105 | 3855 | 3980 | 4105 | mV |
| $\mathrm{V}_{\mathrm{OL}}$ | Output LOW Voltage (Note 12) | 3005 | 3180 | 3305 | 3005 | 3180 | 3305 | 3005 | 3180 | 3305 | mV |
| $\mathrm{V}_{\mathrm{IH}}$ | Input HIGH Voltage (Single-Ended) | -1225 |  | -885 | -1225 |  | -885 | -1225 |  | -885 | mV |
| $\mathrm{V}_{\mathrm{IL}}$ | Input LOW Voltage (Single-Ended) | -1995 |  | -1625 | -1995 |  | -1625 | -1995 |  | -1625 | mV |
| $\mathrm{V}_{\text {BB }}$ | Output Voltage Reference | -1525 | -1425 | -1325 | -1525 | -1425 | -1325 | -1525 | -1425 | -1325 | mV |
| $\mathrm{V}_{\text {IHCMR }}$ | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 13) | $\mathrm{V}_{\mathrm{EE}+2.0}$ |  | 0.0 | $\mathrm{V}_{\mathrm{EE}+2.0}$ |  | 0.0 | $\mathrm{V}_{\mathrm{EE}+2.0}$ |  | 0.0 | V |
| IIH | Input HIGH Current |  |  | 150 |  |  | 150 |  |  | 150 | $\mu \mathrm{A}$ |
| IIL | Input LOW Current | 0.5 |  |  | 0.5 |  |  | 0.5 |  |  | $\mu \mathrm{A}$ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 Ifpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
11. Input and output parameters vary $1: 1$ with $\mathrm{V}_{\mathrm{CC}}$.
12. All loading with $50 \Omega$ to $\mathrm{V}_{\mathrm{cc}}-2.0 \mathrm{~V}$.
13. $\mathrm{V}_{\text {IHCMR }}$ min varies $1: 1$ with $\mathrm{V}_{E E}$, max varies $1: 1$ with $\mathrm{V}_{\mathrm{CC}}$.. The $\mathrm{V}_{\text {IHCMR }}$ range is referenced to the most positive side of the differential input signal.

Table 9. AC CHARACTERISTICS $\mathrm{V}_{\mathrm{EE}}=-3.0 \mathrm{~V}$ to $-5.5 \mathrm{~V} ; \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ to 5.5 V ; $\mathrm{GND}=0 \mathrm{~V}$ (Note 14)

| Symbol | Characteristic | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max |  |
| $\mathrm{f}_{\text {max }}$ | Maximum Frequency (See Figure $2 \mathrm{~F}_{\text {max }} / \mathrm{JITTER}$ ) |  | > 3 |  |  | > 3 |  |  | >3 |  | GHz |
| $\begin{aligned} & \text { tpLH, } \\ & \text { tPHL } \end{aligned}$ | Propagation Delay to Output Differential | 170 | 240 | 310 | 200 | 260 | 340 | 230 | 300 | 370 | ps |
| tskew | Duty Cycle Skew (Note 15) |  | 5.0 | 20 |  | 5.0 | 20 |  | 5.0 | 20 | ps |
|  | Within Device Skew $\quad$ Q, $\overline{\text { Q }}$ Device to Device Skew (Note 15) |  |  | $\begin{gathered} \hline 80 \\ 140 \end{gathered}$ |  |  | $\begin{gathered} \hline 80 \\ 140 \end{gathered}$ |  |  | $\begin{gathered} 80 \\ 140 \end{gathered}$ |  |
| $\mathrm{t}_{\text {IITTER }}$ | Cycle-to-Cycle Jitter (See Figure $2 \mathrm{~F}_{\text {max }} /$ IITTER) |  | 0.2 | < 1 |  | 0.2 | <1 |  | 0.2 | <1 | ps |
| $\mathrm{V}_{\mathrm{PP}}$ | Input Voltage <br> Swing (Differential Configuration) | 150 | 800 | 1200 | 150 | 800 | 1200 | 150 | 800 | 1200 | mV |
| $\begin{aligned} & \mathrm{t}_{\mathrm{r}} \\ & \mathrm{t}_{\mathrm{f}} \end{aligned}$ | Output Rise/Fall Times $(20 \%-80 \%)$$\quad$ Q, $\bar{Q}$ | 70 | 120 | 170 | 80 | 130 | 180 | 100 | 150 | 230 | ps |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm . Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
14. Measured using a 750 mV source, $50 \%$ duty cycle clock source. All loading with $50 \Omega$ to $\mathrm{V}_{\mathrm{CC}}-2.0 \mathrm{~V}$.
15. Skew is measured between outputs under identical transitions. Duty cycle skew is defined only for differential operation when the delays are measured from the cross point of the inputs to the cross point of the outputs.


Figure 2. $\mathrm{F}_{\text {max }} / \mathrm{Jitt}$ r

## MC10EP90, MC100EP90



Figure 3. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020/D - Termination of ECL Logic Devices.)

## ORDERING INFORMATION

| Device | Package | Shipping ${ }^{\dagger}$ |
| :---: | :---: | :---: |
| MC10EP90DTG | $\begin{aligned} & \text { TSSOP-20 } \\ & \text { (Pb-Free) } \end{aligned}$ | 75 Units / Rail |
| MC10EP90DTR2G |  | 2500 / Tape \& Rail |
| MC100EP90DTG |  | 75 Units / Rail |
| MC100EP90DTR2G |  | 2500 / Tape \& Rail |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Resource Reference of Application Notes
AN1405/D - ECL Clock Distribution Techniques
AN1406/D - Designing with PECL (ECL at +5.0 V)
AN1503/D - ECLinPS $^{\text {mN }}$ I/O SPiCE Modeling Kit
AN1504/D - Metastability and the ECLinPS Family
AN1568/D - Interfacing Between LVDS and ECL
AN1672/D - The ECL Translator Guide
AND8001/D - Odd Number Counters Design
AND8002/D - Marking and Date Codes
AND8020/D - Termination of ECL Logic Devices
AND8066/D - Interfacing with ECLinPS
AND8090/D - AC Characteristics of ECL Devices

TSSOP-20 WB
CASE 948E
ISSUE D
DATE 17 FEB 2016

SCALE 2:1


1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
CONTROLLING DIMENSION: MILLIMETER
2. DIMENSION A DOES NOT INCLUDE MOLD

FLASH, PROTRUSIONS OR GATE BURRS.
FLASH, PROTRUSIONS OR GATE BURRS.
MOLD FLASH OR GATE BURRS SHALL NO
EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE

INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION. SHALL NOT EXCEED $0.25(0.010)$ PER SIDE
5. DIMENSION K DOES NOT INCLUDE

DAMBAR PROTRUSION. ALLOWABLE
DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-

|  | MILLIMETERS |  | INCHES |  |
| :---: | :---: | :---: | :---: | :---: |
| DIM | MIN | MAX | MIN | MAX |
| A | 6.40 | 6.60 | 0.252 | 0.260 |
| B | 4.30 | 4.50 | 0.169 | 0.177 |
| C | --- | 1.20 | --- | 0.047 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.50 | 0.75 | 0.020 | 0.030 |
| G | 0.65 BSC |  | 0.026 BSC |  |
| H | 0.27 | 0.37 | 0.011 | 0.015 |
| J | 0.09 | 0.20 | 0.004 | 0.008 |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 |
| K | 0.19 | 0.30 | 0.007 | 0.012 |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 |
| L | 6.40 | BSC | 0.252 BSC |  |
| M | 0 | $0^{\circ}$ | $8^{\circ}$ | 0 |

GENERIC MARKING DIAGRAM* НРННННННН

|  | XXXX |
| :---: | :---: |
|  | XXXX |
|  | ALYW. |
| $\bigcirc$ | - |

A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week

- = Pb-Free Package
(Note: Microdot may be in either location)
*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-$ Free indicator, " G " or microdot " $\mathrm{\nabla}$ ", may or may not be present.
DIMENSIONS: MILLIMETERS

| DOCUMENT NUMBER: | 98ASH70169A | Electronic versions are uncontrolled except when accessed directly from the Document Repository. <br> Printed versions are uncontroled except when stamped "CONTROLLED COPY" in red. |
| ---: | :--- | :--- | :--- |
| DESCRIPTION: | TSSOP-20 WB | PAGE 1 OF 1 |

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[^0]:    *For additional information on our $\mathrm{Pb}-$ Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

